## NSN 5961-01-470-6608

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-470-6608 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 1.500 inches Overall Diameter: Between 0.085 inches and 0.130 inches **Mounting Facility Quantity:** 2 **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 17.0 regulator voltage and 13.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.30 amperes forward current, average peak and 22.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 175.0 degrees celsius case **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/435 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No